

SLG7RN45753

GreenPAK ™

Enya Button Controller

General Description

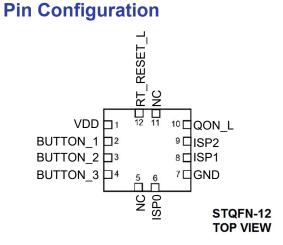
Dialog SLG7RN45753 is a low power and small form device. The SoC is housed in a 1.6mm x 1.6mm STQFN package which is optimal for using with small devices.

Features

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 12 Package

Output Summary

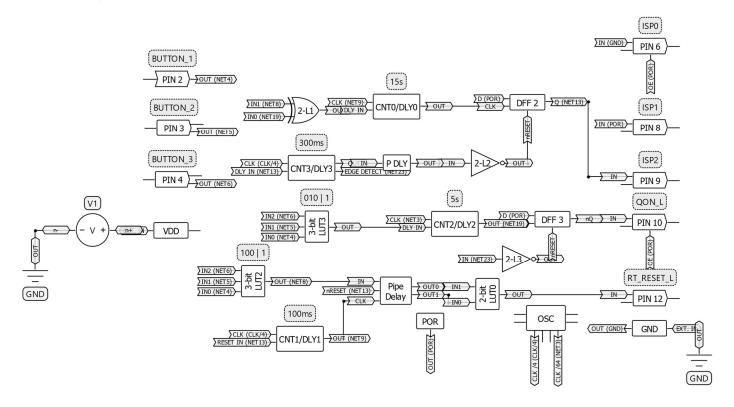
- 3 Outputs Open Drain NMOS 1X
- 2 Outputs Push Pull 1X







Block Diagram







Pin Configuration

Pin #	Pin Name	Туре	Pin Description	Internal Resistor	
1	VDD	PWR	Supply Voltage		
2	BUTTON_1	Digital Input	Digital Input without Schmitt trigger	floating	
3	BUTTON_2	Digital Input	Digital Input without Schmitt trigger	floating	
4	BUTTON_3	Digital Input	Digital Input without Schmitt trigger	floating	
5	NC		Keep Floating or Connect to GND		
6	ISP0	Digital Output	Push Pull 1X	floating	
7	GND	GND	Ground		
8	ISP1	Digital Output	Open Drain NMOS 1X	floating	
9	ISP2	Digital Output	Push Pull 1X	floating	
10	QON_L	Digital Output	Open Drain NMOS 1X	floating	
11	NC		Keep Floating or Connect to GND		
12	RT_RESET_L	Digital Output	Open Drain NMOS 1X	floating	

Ordering Information

Part Number	Package Type
SLG7RN45753V	V=STQFN-12
SLG7RN45753VTR	STQFN-12 – Tape and Reel (3k units)





Absolute Maximum Conditions

Parameter	Min.	Max.	Unit	
Supply Voltage on VDD relative	-0.5	7	V	
DC Input Voltage		GND - 0.5V	VDD + 0.5V	V
Maximum Average or DC Current				mA
(Through pin)		18	IIIA	
Current at Input Pin		-1.0	1.0	mA
Input leakage (Absolute Valu	le)		1000	nA
Storage Temperature Rang	je	-65	150	°C
Junction Temperature		150	°C	
ESD Protection (Human Body M	2000		V	
ESD Protection (Charged Device	1000		V	
Moisture Sensitivity Level		1		

Electrical Characteristics

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
V _{DD}	Supply Voltage		2.3	3.3	5.5	V
TA	Operating Temperature		-40	25	125	°C
CVDD	Capacitor Value at VDD			0.1		μF
CIN	Input Capacitance			4		pF
lq	Quiescent Current	Static inputs and floating outputs PIN2, PIN3 and PIN4 are low		7		μA
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD	V
	Maximum Average or DC	T _J = 85°C			73	mA
IVDD	Current Through VDD Pin (Per chip side, see Note 2)	T _J = 110°C			35	mA
	Maximum Average or DC	T _J = 85°C			92	mA
Ignd	Current Through GND Pin (Per chip side, see Note 2)	T _J = 110°C			44	mA
	HIGH-Level Input Voltage	Logic Input at VDD=1.8V	1.1		VDD	V
Vін		Logic Input at VDD=3.3V	1.78		VDD	V
		Logic Input at VDD=5.0V	2.64		VDD	V
		Logic Input at VDD=1.8V	0		0.69	V
VIL	LOW-Level Input Voltage	Logic Input at VDD=3.3V	0		1.21	V
		Logic Input at VDD=5.0V	0		1.84	V
		Push-Pull 1X, I _{OH} =100µA, at VDD=1.8V	1.68	1.79		V
Vон	HIGH-Level Output Voltage	Push-Pull 1X, I _{OH} =3mA, at VDD=3.3V	2.71	3.09		V
		Push-Pull 1X, I _{OH} =5mA, at VDD=5.0V	4.15	4.73		V
		Push-Pull 1X, I₀∟=100µA, at VDD=1.8V		0.02	0.03	V
Vol	LOW-Level Output Voltage	Push-Pull 1X, I _{OL} =3mA, at VDD=3.3V		0.18	0.28	V
		Push-Pull 1X, I₀∟=5mA, at VDD=5.0V		0.23	0.33	V





					-	
		Open Drain NMOS 1X, I _{OL} =100µA, at VDD=1.8V		0.01	0.02	V
		Open Drain NMOS 1X, Io∟=3mA, at VDD=3.3V		0.09	0.13	V
		Open Drain NMOS 1X, Io∟=5mA, at VDD=5.0V		0.12	0.16	V
		Push-Pull 1X, V _{OH} =VDD- 0.2V, at VDD=1.8V	1.04	1.4		mA
I _{ОН}	HIGH-Level Output Current (Note 1)	Push-Pull 1X, V _{OH} =2.4V, at VDD=3.3V	5.83	10.18		mA
	()	Push-Pull 1X, V _{OH} =2.4V, at VDD=5.0V	21.808	29.1		mA
		Push-Pull 1X, Vo∟=0.15V, at VDD=1.8V	0.76	1.34		mA
		Push-Pull 1X, V _{OL} =0.4V, at VDD=3.3V	4.06	6.44		mA
	LOW-Level Output Current VDD=5.0V		6.01	9.73		mA
lol	(Note 1)	Open Drain NMOS 1X, Vo∟=0.15V, at VDD=1.8V	1.53	2.67		mA
		Open Drain NMOS 1X, V _{OL} =0.4V, at VDD=3.3V	8.13	12.41		mA
		Open Drain NMOS 1X, V _{OL} =0.4V, at VDD=5.0V	11.76	19.46		mA
		At temperature 25°C	14.34	15.02	16.36	s
T _{DLY0}	Delay0 Time	At temperature -40 +125°C (Note 3)	13.45	15.02	19.14	s
		At temperature 25°C	4.78	5.01	5.31	S
T _{DLY2}	Delay2 Time	At temperature -40 +125°C (Note 3)	4.49	5.01	6.21	s
		At temperature 25°C	286.8	300.1	317.9	ms
T _{DLY3}	Delay3 Time	At temperature -40 +125°C (Note 3)	269.1	300.1	372.0	ms
		At temperature 25°C	95.6	99.8	108.3	ms
T _{CNT1}	Counter1 Period	At temperature -40 +125°C (Note 3)	89.7	99.8	126.7	ms
Tsu	Startup Time	From VDD rising past 1.35 V		0.27		ms
PONTHR	Power On Threshold	VDD Level Required to Start Up the Chip	1.182	1.346	1.505	V
POFFTHR	Power Off Threshold	V _{DD} Level Required to Switch Off the Chip	0.752	0.918	1.11	V
lote:						

Note:

1. DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.

2. The GreenPAK's power rails are divided in two sides. Pins 2, 3, 4 and 6 are connected to one side, pins 8, 9, 10 and 12 to another.

3. Guaranteed by Design.





Functionality Waveforms

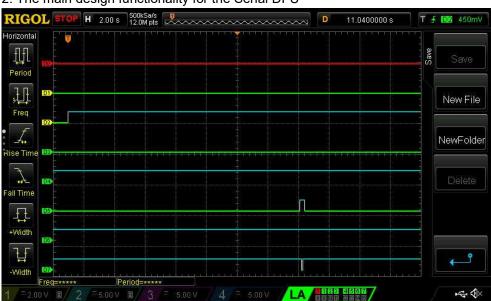
- D0 PIN#2 (BUTTON_1)
- D1 PIN#3 (BUTTON_2)
- D2 PIN#4 (BUTTON_3)
- D3 PIN#6 (ISP0)
- D4-PIN#8 (ISP1) with external $5k\Omega$ pull up resistor
- D5 PIN#9 (ISP2)
- $D6-PIN\#10~(QON_L)$ with external $5k\Omega$ pull up resistor
- D7 PIN#12 (RT_RESET_L) with external $5k\Omega$ pull up resistor

1. The main design functionality for the Power Cycle



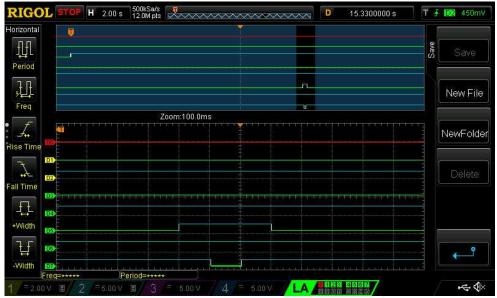






2. The main design functionality for the Serial DFU

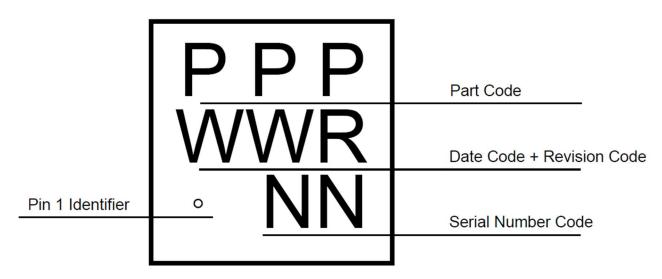
3. Zoomed WF#2







Package Top Marking



Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Revision	Date
0.10	001	U	0xC60CCE74			05/06/2022

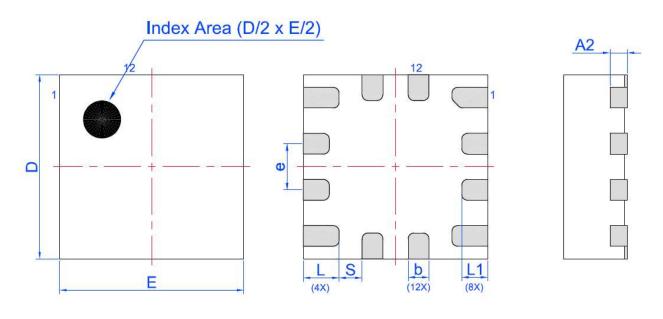
The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.





Package Drawing and Dimensions

12 Lead STQFN FC Package 1.6 x 1.6 mm IC net weight: 0.0028 g





Unit: mm Symbol Symbol Min Nom. Max Min Nom. Max 0.60 0.55 1.55 A 0.50 D 1.60 1.65 0.060 A1 Е 0.005 1.55 1.60 1.65 -A2 0.10 0.15 0.20 0.26 0.31 0.36 L 0.13 0.18 0.23 L1 0.175 0.225 0.275 b 0.40 BSC S 0.2 REF е





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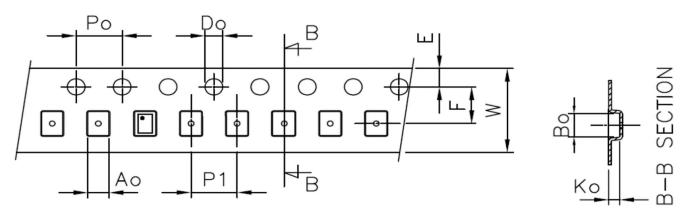
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Tape and Reel Specification

		Nominal	Max	Units		Leade	r (min)	Trailer	' (min)	Таре	Part
Package Type	# of Pins	Package Size [mm]	per Reel	per Box	Reel & Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 12L FC 0.4P Green	12	1.6x1.6x0.55	3000	3000	178/60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	B0	K0	P0	P1	D0	E	F	w
STQFN 12L FC 0.4P Green	1.8±0.05	1.8±0.05	±0.7	4	4	1.5	1.75	3.5	8



Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 1.408 mm³ (nominal). More information can be found at <u>www.jedec.org.</u>

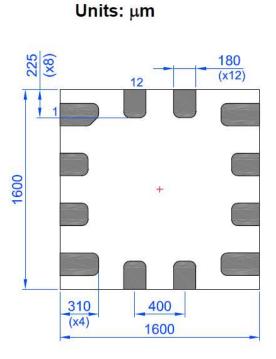




Recommended Land Pattern

Exposed Pad (PKG face down)

Recommended Land Pattern (PKG face down) 1900 970 390 (x4) 12 1 180 1120 1900 190 465 190 (x8) 210 (x12)









Datasheet Revision History

Date	Version	Change
05/06/2022	0.10	New design for SLG46110 chip



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